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Trench IGBT Modules

SEMiX303GB17E4p

Features*

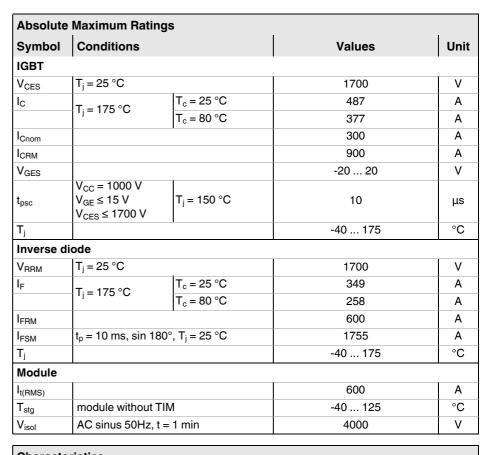
- · Homogeneous Si
- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability
- · Press-fit pins as auxiliary contacts
- UL recognized, file no. E63532

Typical Applications

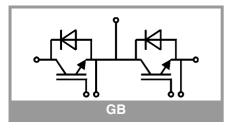
- · AC inverter drives
- UPS
- Renewable energy systems

Remarks

- Product reliability results are valid for T_i=150°C
- V_{isol} between temperature sensor and power section is only 2500V
- For storage and case temperature with TIM see document "TP(*) SEMiX 3p"



Characteristics									
Symbol	Conditions		min.	typ.	max.	Unit			
IGBT									
V _{CE(sat)}	$I_{C} = 300 \text{ A}$ $V_{GE} = 15 \text{ V}$ chiplevel	T _j = 25 °C		1.90	2.20	V			
		T _j = 150 °C		2.29	2.60	V			
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V			
		T _j = 150 °C		0.70	0.80	V			
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		3.7	4.3	$m\Omega$			
		T _j = 150 °C		5.3	6.0	mΩ			
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 12 \text{ mA}$		5.2	5.8	6.4	V			
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 17$			4.0	mA				
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		27.0		nF			
Coes		f = 1 MHz		1.02		nF			
C _{res}		f = 1 MHz		0.87		nF			
Q_G	V _{GE} = - 8 V+ 15 V			2400		nC			
R _{Gint}	T _j = 25 °C			2.5		Ω			
t _{d(on)}	$\begin{array}{l} I_{C} = 300 \; A \\ V_{GE} = +15/\text{-}15 \; V \\ R_{G \; on} = 1 \; \Omega \\ R_{G \; off} = 1 \; \Omega \\ di/dt_{on} = 5700 \; A/\mu s \\ di/dt_{off} = 1600 \; A/\mu s \end{array}$	T _j = 150 °C		270		ns			
t _r		T _j = 150 °C		54		ns			
E _{on}		T _j = 150 °C		76		mJ			
t _{d(off)}		T _j = 150 °C		630		ns			
t _f		T _j = 150 °C		160		ns			
E _{off}		T _j = 150 °C		99		mJ			
R _{th(j-c)}	per IGBT				0.08	K/W			
R _{th(c-s)}	per IGBT (λ _{grease} =0.81 W/(m*K))			0.029		K/W			
R _{th(c-s)}	per IGBT, pre-appli material		0.02		K/W				





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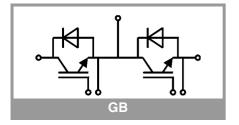
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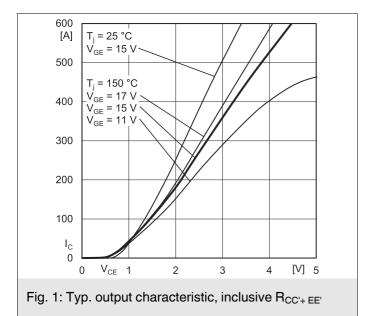
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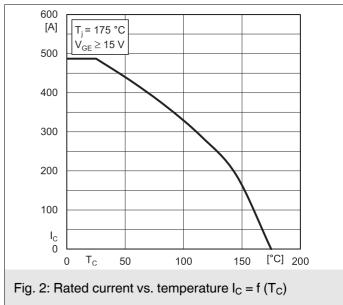
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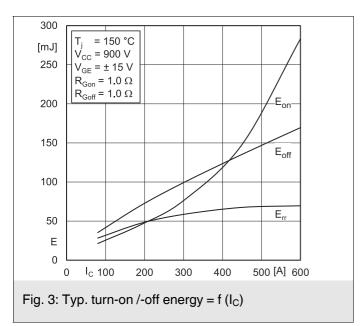
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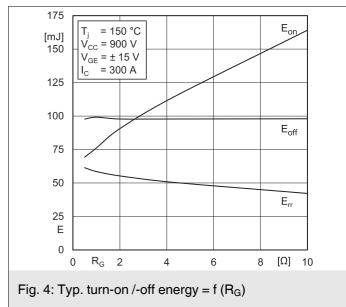
Characteristics										
Symbol	Conditions		min.	typ.	max.	Unit				
Inverse diode										
$V_F = V_{EC}$	I _F = 300 A	T _j = 25 °C		2.00	2.40	V				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.16	2.57	٧				
V _{F0}	chiplevel	T _j = 25 °C		1.32	1.56	V				
		T _j = 150 °C		1.08	1.22	V				
r _F	chiplevel	T _j = 25 °C		2.3	2.8	mΩ				
		T _j = 150 °C		3.6	4.5	mΩ				
I _{RRM}	$I_F = 300 \text{ A}$ $di/dt_{off} = 6050 \text{ A/}\mu\text{s}$ $V_{GE} = -15 \text{ V}$ $V_{CC} = 900 \text{ V}$	T _j = 150 °C		374		Α				
Q _{rr}		T _j = 150 °C		93		μC				
E _{rr}		T _j = 150 °C		59		mJ				
R _{th(j-c)}	per diode				0.16	K/W				
R _{th(c-s)}	per diode (λ _{grease} =0.81 W/(m*K))			0.048		K/W				
R _{th(c-s)}	per diode, pre-applied phase change material			0.038		K/W				
Module						•				
L _{CE}				20		nΗ				
R _{CC'+EE'}	measured per switch	T _C = 25 °C		1.2		mΩ				
		T _C = 150 °C		1.65		mΩ				
R _{th(c-s)1}	calculated without t		0.009		K/W					
R _{th(c-s)2}	including thermal c T _s underneath mod (m*K))		0.014		K/W					
R _{th(c-s)2}	including thermal coupling, T _s underneath module, pre-applied phase change material			0.010		K/W				
Ms	to heat sink (M5)		3		6	Nm				
Mt		to terminals (M6)	3		6	Nm				
						Nm				
W					350	g				
Temperat	ture Sensor									
R ₁₀₀	T _c =100°C (R ₂₅ =5 kΩ)			493 ± 5%		Ω				
B _{100/125}	$R_{(T)} = R_{100} exp[B_{100/125}(1/T-1/T_{100})]; T[K];$			3550 ±2%		К				

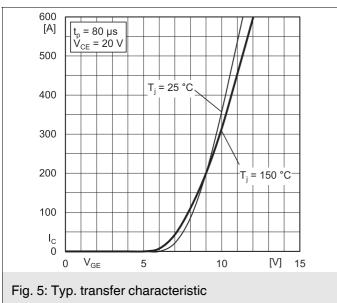


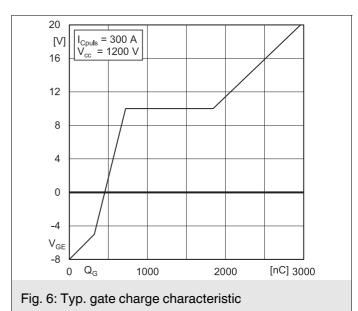


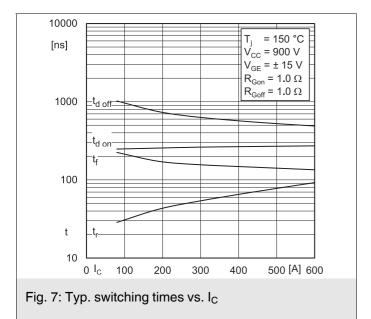


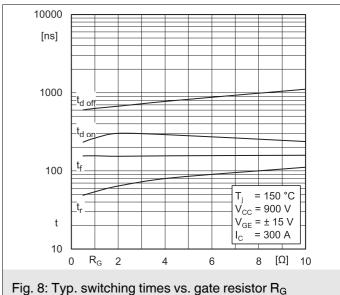


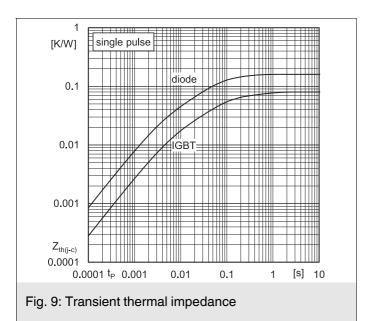


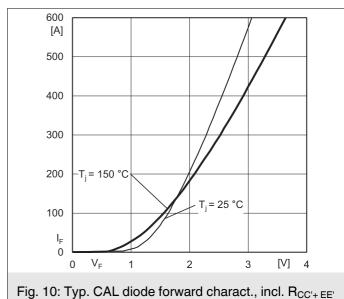


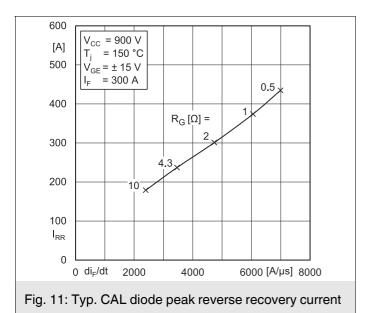


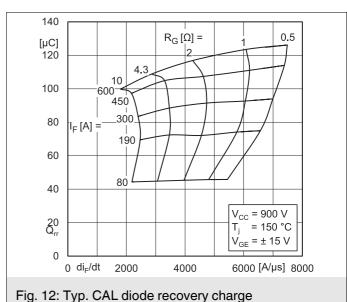


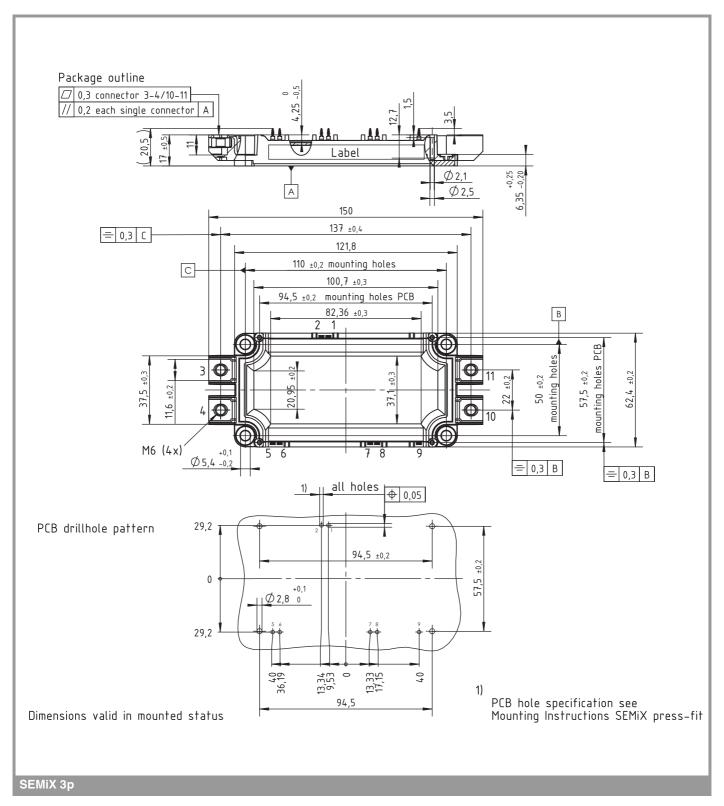


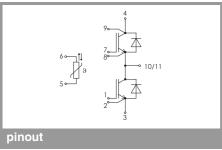












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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